COMPLEMENTARY SILICON TRANSISTORS

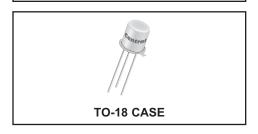


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DESCRIPTION:

The CENTRAL SEMICONDUCTOR 2N6430 series devices are complementary small signal silicon transistors manufactured by the epitaxial planar process, designed for high voltage amplifier applications.

MARKING: FULL PART NUMBER



| MAXIMUM RATINGS: (T _A =25°C unless otherwise noted) | | 2N6430 | 2N6431 | |
|--|-----------------------------------|--------|--------|-------|
| • • | SYMBOL | 2N6432 | 2N6433 | UNITS |
| Collector-Base Voltage | V_{CBO} | 200 | 300 | V |
| Collector-Emitter Voltage | V _{CEO} | 200 | 300 | V |
| Emitter-Base Voltage (NPN) | V_{EBO} | 6.0 | | V |
| Emitter-Base Voltage (PNP) | V_{EBO} | 5. | 0 | V |
| Continuous Collector Current | I _C | 50 | 0 | mA |
| Power Dissipation (T _C =25°C) | P_{D} | 1. | 8 | W |
| Power Dissipation | P_{D} | 50 | 0 | mW |
| Operating and Storage Junction Temperature | T _J , T _{stg} | -65 to | +200 | °C |
| Thermal Resistance | $\Theta_{\sf JA}$ | 0.3 | 35 | °C/mW |
| Thermal Resistance | Θ JC | 97 | .2 | °C/W |

| ELECTRICAL | LECTRICAL CHARACTERISTICS: (T _A =25°C) | | 2N6430 2N6431 | | 2N6432 2N6433 | |
|-----------------------|---|-----|------------------|-----|------------------|-------|
| SYMBOL | TEST CONDITIONS | MIN | MAX | MIN | MAX | UNITS |
| ICBO | V _{CB} =160V (2N6430, 2N6432) | - | 100 | - | 250 | nA |
| I _{CBO} | V _{CB} =200V (2N6431, 2N6433) | - | 100 | - | 250 | nA |
| I _{EBO} | V _{EB} =4.0V | - | 100 | - | - | nA |
| I _{EBO} | V _{EB} =3.0V | - | - | - | 100 | nA |
| BV_{CBO} | I _C =100μA (2N6430, 2N6432) | 200 | - | 200 | - | V |
| BV _{CBO} | I _C =100μA (2N6431, 2N6433) | 300 | - | 300 | - | V |
| BV _{CEO} | I _C =1.0mA (2N6430, 2N6432) | 200 | - | 200 | - | V |
| BV _{CEO} | I _C =1.0mA (2N6431, 2N6433) | 300 | - | 300 | - | V |
| BVEBO | I _E =100μA | 6.0 | - | 5.0 | - | V |
| V _{CE} (SAT) | I _C =20mA, I _B =2.0mA | - | 0.5 | - | 0.5 | V |
| V _{BE(SAT)} | I _C =20mA, I _B =2.0mA | - | 0.9 | - | 0.9 | V |
| h _{FE} | V _{CE} =10V, I _C =1.0mA | 25 | - | 25 | - | |
| h _{FE} | V _{CE} =10V, I _C =10mA | 40 | - | 40 | - | |
| h _{FE} | V_{CE} =10V, I_{C} =30mA | 50 | 200 | 30 | 150 | |

R2 (3-April 2018)

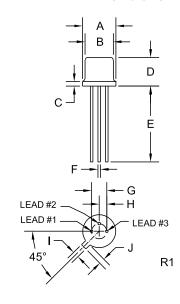
COMPLEMENTARY SILICON TRANSISTORS



ELECTRICAL CHARACTERISTICS - Continued: (T_A=25°C)

| SYMBOL TEST CONDITIONS | | 2N6430 2N6431 | | 2N6432 2N6433 | | |
|------------------------|---|------------------|-----|------------------|-----|-------|
| | TEST CONDITIONS | MIN | MAX | MIN | MAX | UNITS |
| f_{T} | V_{CE} =20V, I_{C} =10mA, f=100MHz | 50 | 200 | - | - | MHz |
| fT | V_{CE} =20V, I_{C} =10mA, f=20MHz | - | - | 50 | - | MHz |
| C _{ob} | V _{CB} =20V, I _E =0, f=1.0MHz | - | 4.0 | - | 6.0 | pF |

TO-18 CASE - MECHANICAL OUTLINE



| DIMENSIONS | | | | | |
|------------|--------|-------|-------------|------|--|
| | INCHES | | MILLIMETERS | | |
| SYMBOL | MIN | MAX | MIN | MAX | |
| A (DIA) | 0.209 | 0.230 | 5.31 | 5.84 | |
| B (DIA) | 0.178 | 0.195 | 4.52 | 4.95 | |
| С | - | 0.030 | - | 0.76 | |
| D | 0.170 | 0.210 | 4.32 | 5.33 | |
| E | 0.500 | - | 12.70 | - | |
| F (DIA) | 0.016 | 0.019 | 0.41 | 0.48 | |
| G (DIA) | 0.100 | | 2.54 | | |
| Н | 0.050 | | 1.27 | | |
| I | 0.036 | 0.046 | 0.91 | 1.17 | |
| J | 0.028 | 0.048 | 0.71 | 1.22 | |

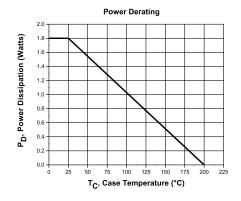
TO-18 (REV: R1)

LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector

MARKING:

FULL PART NUMBER

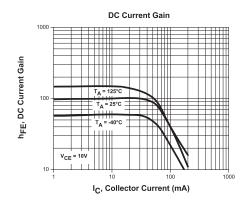


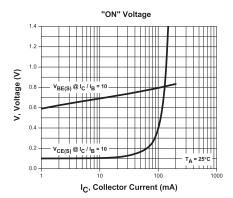
R2 (3-April 2018)

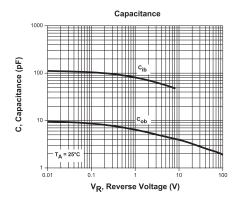




NPN TYPICAL ELECTRICAL CHARACTERISTICS



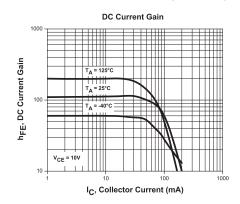


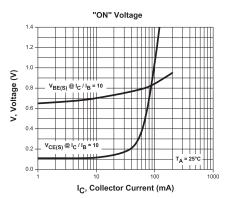


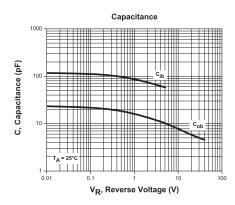




PNP TYPICAL ELECTRICAL CHARACTERISTICS









OUTSTANDING SUPPORT AND SUPERIOR SERVICES

PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- Custom bar coding for shipments
- · Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- · Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- Special wafer diffusions
- · PbSn plating options
- · Package details
- · Application notes
- · Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

Corporate Headquarters & Customer Support Team

Central Semiconductor Corp. 145 Adams Avenue Hauppauge, NY 11788 USA Main Tel: (631) 435-1110 Main Fax: (631) 435-1824

Support Team Fax: (631) 435-3388

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